High-reliability discrete products and engineering services since 1977

1N821-1N829A

## TEMPERATURE COMPENSATED ZENER REFERENCE DIODE

## FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.


## MAXIMUM RATINGS

| Operating and storage temperature range | $-65^{\circ} \mathrm{C}$ to $+175^{\circ} \mathrm{C}$ |
| :--- | :--- |
| DC power dissipation | $500 \mathrm{~mW} @ \mathrm{~T}_{\mathrm{L}}=25^{\circ} \mathrm{C}$ and maximum current $\mathrm{I}_{\mathrm{ZM}} \mathrm{OF} 70 \mathrm{~mA}$. <br> For optimum voltage-temperature stability, $\mathrm{I}_{\mathrm{Z}}=7.5 \mathrm{~mA}$ <br> (less than 50 mW in dissipated power) |
| Solder temperatures | $260^{\circ} \mathrm{C}$ for 10 s (max) |

ELECTRICAL CHARACTERISTICS $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)

| Part number | Zener voltage <br> (Note 1 and 4) $\mathrm{V}_{\mathrm{z}} @ \mathrm{I}_{\mathrm{ZT}}$ | Zener Test Current $\mathrm{I}_{\mathrm{ZT}}$ | Maximum zener impedance <br> (Note 2) $\mathrm{Z}_{\mathrm{ZT}} @ \mathrm{I}_{\mathrm{ZT}}$ | Maximum reverse current IR @ 3V | Voltage temperature stability ( $\Delta \mathrm{V}_{\text {zt }} \mathrm{MAX}$ ) $-55^{\circ} \mathrm{C}$ to $=100^{\circ} \mathrm{C}$ (Note 3 and 4) | Effective temperature coefficient $\alpha_{v z}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | VOLTS | mA | OHMS | $\mu \mathrm{A}$ | mV | \%/ ${ }^{\circ} \mathrm{C}$ |
| 1N821 | 5.9-6.5 | 7.5 | 15 | 2.0 | 96 | 0.01 |
| 1N821A | 5.9-6.5 | 7.5 | 10 | 2.0 | 96 | 0.01 |
| 1N822 ${ }^{+}$ | 5.9-6.5 | 7.5 | 15 | 2.0 | 96 | 0.01 |
| 1N823 | 5.9-6.5 | 7.5 | 15 | 2.0 | 48 | 0.005 |
| 1N823A | 5.9-6.5 | 7.5 | 10 | 2.0 | 48 | 0.005 |
| 1N824+ | 5.9-6.5 | 7.5 | 15 | 2.0 | 48 | 0.005 |
| 1N825 | 5.9-6.5 | 7.5 | 15 | 2.0 | 19 | 0.002 |
| 1N825A | 5.9-6.5 | 7.5 | 10 | 2.0 | 19 | 0.002 |
| 1N826 | 6.2-6.9 | 7.5 | 15 | 2.0 | 20 | 0.002 |
| 1N827 | 5.9-6.5 | 7.5 | 15 | 2.0 | 9 | 0.001 |
| 1N827A | 5.9-6.5 | 7.5 | 10 | 2.0 | 9 | 0.001 |
| 1N828 | 6.2-6.9 | 7.5 | 15 | 2.0 | 10 | 0.001 |
| 1N829 | 5.9-6.5 | 7.5 | 15 | 2.0 | 5 | 0.0005 |
| 1N829A | 5.9-6.5 | 7.5 | 10 | 2.0 | 5 | 0.0005 |

† Double Anode; electrical specifications apply under both bias polarities. NOTES:

1. Add a " -1 " suffix for internal metallurgical bond.
2. Zener impedance measured by superimposing 0.75 mA ac rms on $7.5 \mathrm{~mA} \mathrm{dc} @ 25^{\circ} \mathrm{C}$.
3. The maximum allowable change observed over the entire temperature range, i.e. the diode voltage will not exceed the specified mV change at discrete temperature between the established limits.
4. Voltage measurements to be performed 15 seconds after application of dc current.

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TEMPERATURE COMPENSATED ZENER REFERENCE DIODE

MECHANICAL CHARACTERISTICS

| Case | DO-35 |
| :--- | :--- |
| Marking | Alpha-numeric |
| Polarity | Cathode Band |


|  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | D0-35 |  |  |  |
|  | Inches | Millimeters |  |  |
|  | Min | Max | Min | Max |
| BD | 0.055 | 0.090 | 1.400 | 2.290 |
| BL | 0.120 | 0.200 | 3.050 | 5.080 |
| LD | 0.018 | 0.022 | 0.460 | 0.560 |
| LL | 1.000 | 1.500 | 25.400 | 38.100 |

